

# isc Silicon PNP Power Transistor

#### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -140V(Min)
- · Good Linearity of hFE
- Complement to Type 2SD1148
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

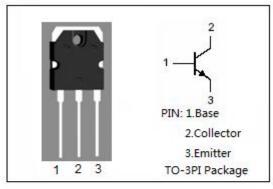


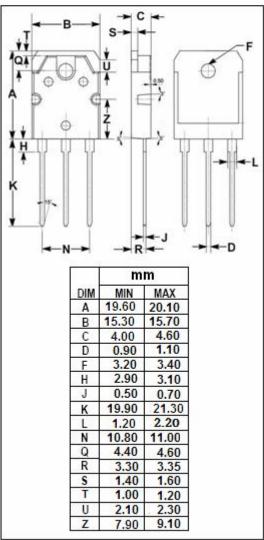
### **APPLICATIONS**

- · Power amplifier applications
- Recommend for 70W high fidelity audio frequency amplifier output stage applications



SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-140	V	
V <sub>CEO</sub>	Collector-Emitter Voltage -140			
V <sub>EBO</sub>	Emitter-Base Voltage -5			
Ic	Collector Current-Continuous	-10	А	
I <sub>B</sub>	Base Current-Continuous	-1	А	
Pc	Collector Power Dissipation @ T <sub>C</sub> =25℃		W	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	







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2SB863

### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -50mA; I <sub>B</sub> = 0	-140			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -5.0A; I <sub>B</sub> = -0.5A			-2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -5A; V <sub>CE</sub> = -5V			-1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -140V; I <sub>E</sub> = 0			-5	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-5	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	55		160	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -5A; V <sub>CE</sub> = -5V	25			
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = -10V; f <sub>test</sub> = 1.0MHz		400		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> =-1A; V <sub>CE</sub> = -10V		15		MHz

## ♦ h<sub>FE-1</sub> Classifications

R	0		
55-110	80-160		

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